
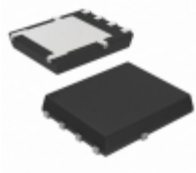
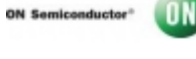
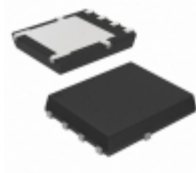
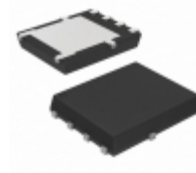
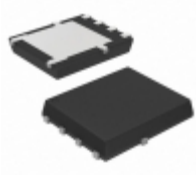
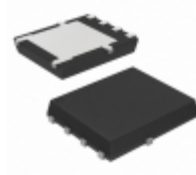
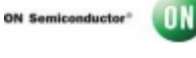
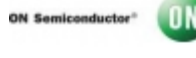
	<h2 style="color: red;">NVMFS5113PLT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS5113PLT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 64A SO8FL</p> <p>Datenblätter:  NVMFS5113PLT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS5113PLT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 60V 64A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1500 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	3.8W (Ta), 150W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Ta), 64A (Tc)
Rds On (Max) @ Id, Vgs	14 mOhm @ 17A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	83nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4400pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®

NVMFS5113PLT1G ist neu im Original, Suche NVMFS5113PLT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVMFS5113PLT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVMFS5113PLT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVMFS5826NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 26A SO8FL</p>	 <p>NVMFS4C310NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS5826NLT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 26A SO8FL</p>	 <p>NVMFS5113PLWFT1G AMI Semiconductor / ON Semiconductor NFET SO8FL 60V 69A 16MOHM</p>
 <p>NVMFS4C302NWFT1G AMI Semiconductor / ON Semiconductor NFET SO8FL 30V 1.15MO</p>	 <p>NVMFS5826NLT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 26A SO8FL</p>	 <p>NVMFS4C310NWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>	 <p>NVMFS4C310NWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V TRENCH</p>

heiße Teile

Mehr

# 06031A6R2CAT2A	↔ A44L-0001-0165	→ AAT3157ITP-T1	D ASMT-RA45-AP932	→ AT5250-1.8KDR
↳ AT93C56SC	# C1608NP02A820J080AA	D C3216CH1H333J085AA	→ C430PX135	→ C5750C0G3A333J280KC
# DV889B-3900-40	↳ FAN54046UCX	# FDMS7656AS	↔ GRM0225C1E4R6CDAEL	→ IS46TR16640A-15GBLA1
D JW075B1-18	# LAE675-U2-3-3A-50	↳ LFE9245E-R	# LM5001IDQ1	→ MC68SEC000FU10
→ MG75J2Y40	↔ MSM51V4805D-60JSFSR1	# NVMD3P03	↳ NVMD3P03R2G	↳ NVMD4N03
↔ NVMD6N04	→ NVMFD5853NLT1G	D NVMFD5877NLT3G	# NVMFD5877NLWFT1G	↳ NVMFSA4C01NWFT1G
# NVMFS4C05N	D NVMFS5830NLWFT1G	→ NVMFS5885NLT3G	↔ NVMFS5C450NT1G	↳ NVMFS5C456NLT1G
↳ NVMFS5C468NLT1G	# PCMC104T1R0MN	↔ PE25FG160	→ PIC93LC46BI-SM	→ PS219B3-S
# SML75EUZ04JD	↳ SN74AHCT16244DGGR	# SN75454BD	D SP207ET-L	→ SP485EMN-L/TR
↔ T828N04TOC	# TDA8275HN/C1	↳ V24A24M400BL	# VE-J63-CW	→ VUE130-12N07

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